

**SD1414-12**

RF & MICROWAVE TRANSISTORS 800-900 MHz APPLICATIONS

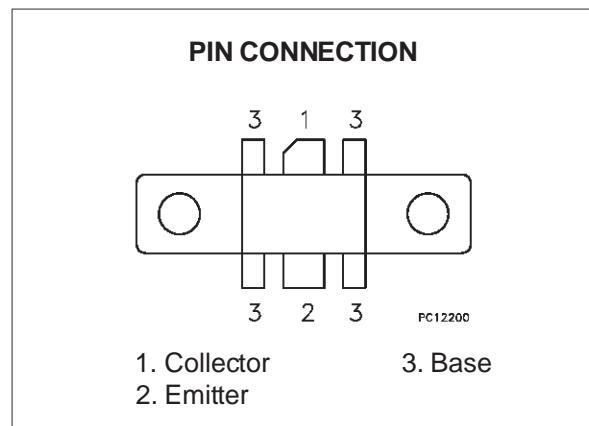
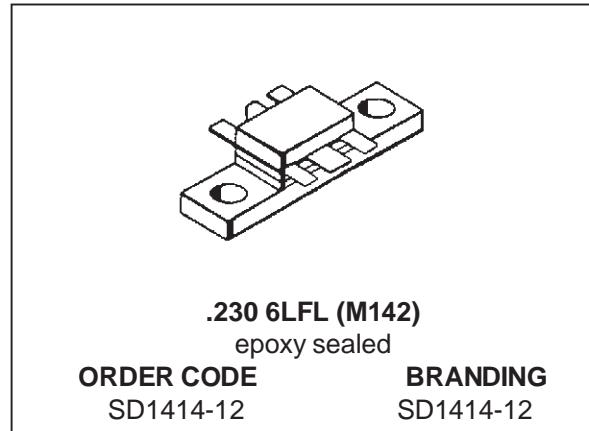
PRELIMINARY DATA

- 960 MHz
- 13.5 VOLTS
- COMMON BASE
- P_{OUT} = 40 W MIN. WITH 4.3 dB gain

DESCRIPTION

The SD1414-12 is a 13.5 V Class C Epitaxial silicon NPN planar transistor designed for amplifier applications up to 960 MHz.

Internal input matching and common base configuration assure optimum gain and efficiency in broad band applications.

**ABSOLUTE MAXIMUM RATINGS (T_{case} = 25 °C)**

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	36	V
V _{CEO}	Collector-Emitter Voltage	18	V
V _{CES}	Collector-Emitter Voltage	36	V
V _{EBO}	Emitter-Base Voltage	4.0	V
I _c	Device Current	9.0	A
P _{DISS}	Power Dissipation	150	W
T _j	Max. Operating Junction Temperature	+200	°C
T _{STG}	Storage Temperature	-65 to 150	°C

THERMAL DATA

R _{th(j-c)}	Junction-Case Thermal Resistance	1.2	°C/W
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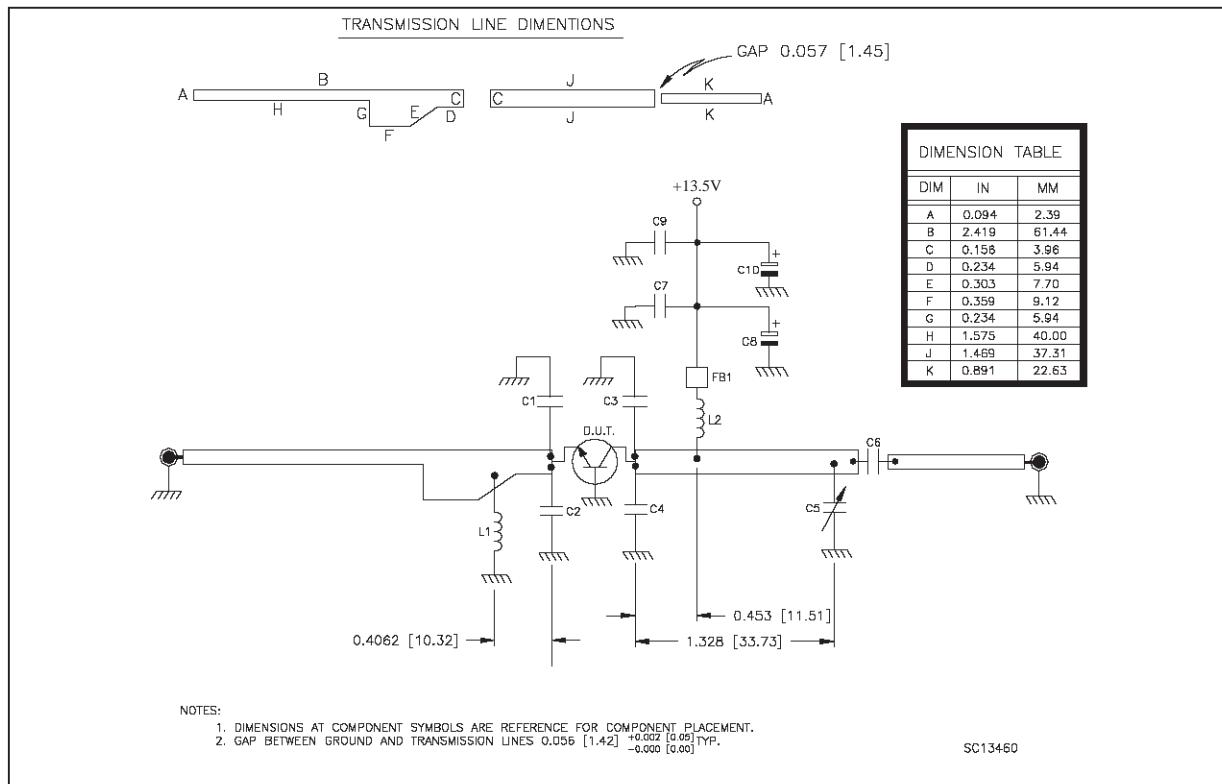
ELECTRICAL SPECIFICATION ($T_{case} = 25^{\circ}\text{C}$)**STATIC**

Symbol	Parameter	Min.	Typ.	Max.	Unit
BV_{CES}	$I_C = 50 \text{ mA}$ $V_{BE} = 0 \text{ V}$	36			V
BV_{CEO}	$I_C = 50 \text{ mA}$ $I_B = 0 \text{ mA}$	18			V
BV_{EBO}	$I_E = 10 \text{ mA}$ $I_C = 0 \text{ mA}$	4.0			V
I_{CBO}	$V_{CB} = 15 \text{ V}$ $I_E = 0 \text{ mA}$			5	mA
h_{FE}	$V_{CE} = 5 \text{ V}$ $I_C = 1 \text{ A}$	20		200	

DYNAMIC

Symbol	Parameter	Min.	Typ.	Max.	Unit
P_{OUT}	$f = 960 \text{ MHz}$ $P_{\text{IN}} = 15 \text{ W}$ $V_{CC} = 13.5 \text{ V}$	40			W
G_P	$f = 960 \text{ MHz}$ $P_{\text{IN}} = 15 \text{ W}$ $V_{CC} = 13.5 \text{ V}$	4.3			dB
η_C	$f = 960 \text{ MHz}$ $P_{\text{IN}} = 15 \text{ W}$ $V_{CC} = 13.5 \text{ V}$		50		%
Load Mismatch	$f = 960 \text{ MHz}$ $P_{\text{IN}} = 15 \text{ W}$ $V_{CC} = 15 \text{ V}$ All Phases	10:1			VSWR
C_{OB}	$f = 1 \text{ MHz}$ $V_{CB} = 13.5 \text{ V}$		80		pF

960 MHz Test Circuit Schematic



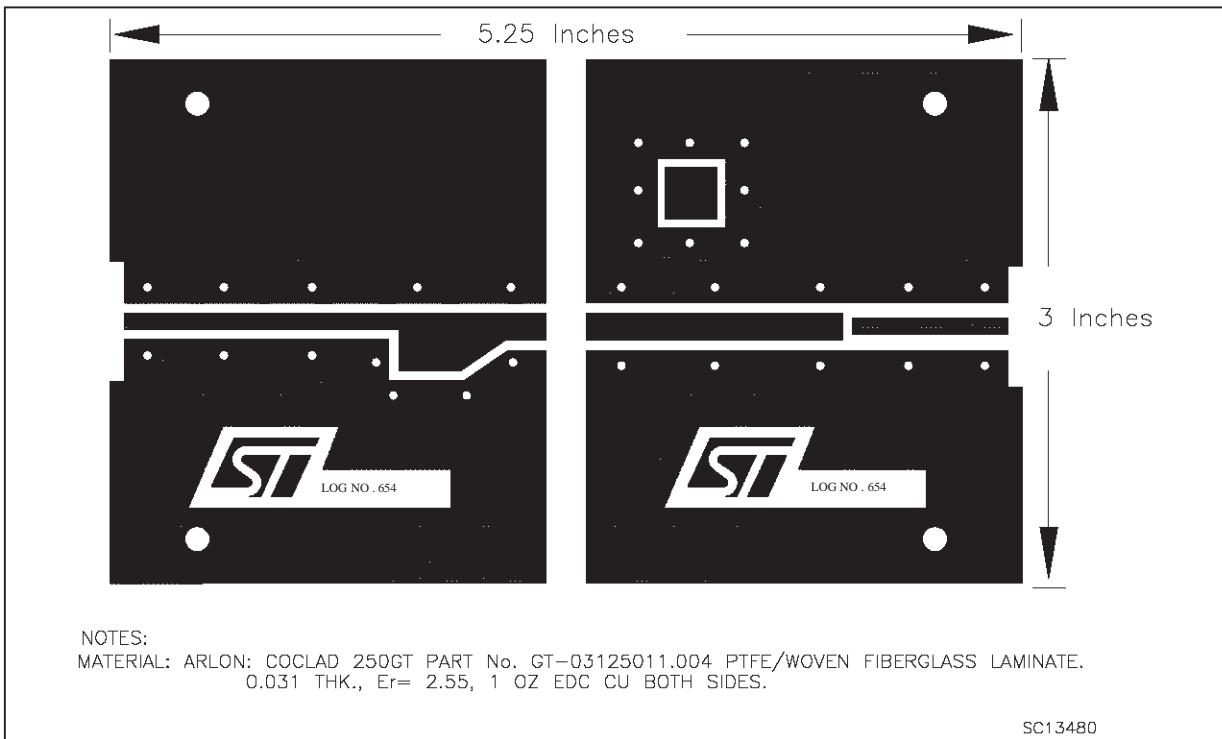
960 MHz Test Circuit Component Part List

ITEM	PART NO	VENDOR	DESCRIPTION
C10	WGR680M1JG18V	MALLORY	68 μ F/63V ALUMINUM ELECTROLYTIC RADIAL LEAD CAPACITOR
C9	MCJ-101ED102J0	ARCO	1000pf/500V METAL CLAD SURFACE MOUNT CAPACITOR
C8	516D106M063JL6A	SPRAGUE	10 μ F/63V ALUMINUM ELECTROLYTIC AXIAL LEAD CAPACITOR
C7	CKR06BX104KR	KEMET	0.1 μ F/100V CERAMIC MOLDED RADIAL LEAD CAPACITOR
C6	ATC100B470KP500X	ATC	47pf ATC 100B SURFACE MOUNT CERAMIC CHIP CAPACITOR
C5	5401PC	JOHANSON	1.0–14pf STANDARD AIR DIELECTRIC VARIABLE CAPACITOR
C4	MUM-602ED150J0	ARCO	15pf METAL CLAD SURFACE MOUNT CAPACITOR
C3	MUM-602ED200J0	ARCO	20pf METAL CLAD SURFACE MOUNT CAPACITOR
C2	MUM-602ED110J0	ARCO	11pf METAL CLAD SURFACE MOUNT CAPACITOR
C1	MUM-602ED110J0	ARCO	11pf METAL CLAD SURFACE MOUNT CAPACITOR
FB1	2643000101	FAIR-RITE	SHIELD BEAD
L2	TYPE 8076	BELDEN	INDUCTOR, 10 TURN, AIR WOUND, I.D. 0.109 [2.77], 20AWG POLY-COATED MAGNET WIRE
L1	TYPE 8078	BELDEN	INDUCTOR, 12 TURN, AIR WOUND, I.D. 0.080 [2.03], 24AWG POLY-COATED MAGNET WIRE

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960 MHz Test Circuit Photomaster



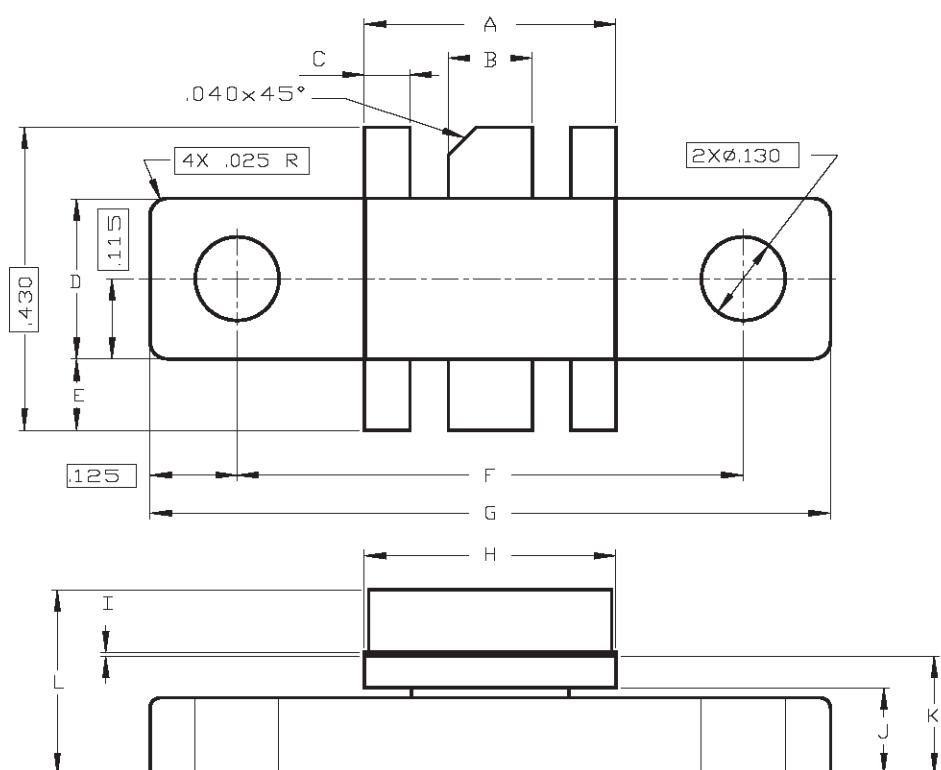
NOTES:

MATERIAL: ARLON: COCLAD 250GT PART No. GT-03125011.004 PTFE/WOVEN FIBERGLASS LAMINATE.
0.031 THK., Er= 2.55, 1 OZ EDC CU BOTH SIDES.

SC13480

M142 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	9.02		9.27	0.355		0.365
B	2.92		3.18	0.115		0.125
C	1.91		2.16	0.075		0.085
D	5.72		5.97	0.225		0.235
E	2.29		2.79	0.090		0.110
F	18.29		18.54	0.720		0.730
G	24.64		24.89	0.970		0.980
H	9.02		9.27	0.355		0.365
I	0.10		0.15	0.004		0.006
J	3.05		3.30	0.120		0.130
K	4.06		4.57	0.160		0.180
L	5.84		6.60	0.230		0.260



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